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Optics of semiconductors from meta-GGA-based time-dependent density-functional theory

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We calculate the optical spectra of silicon, germanium, and zincblende semiconductors in the adiabatic time-dependent density functional formalism, making use of kinetic energy density-dependent (meta-GGA) exchange-correlation functionals. We find excellent agreement between theory and experiment. The success of the theory on this notoriously difficult problem is traced to the fact that the exchange-correlation kernel of meta-GGA supports a singularity of the form α/q^2 (where q is the wave-vector and α is a constant), whereas previously employed approximations (e.g. local density and generalized gradient approximations) do not. Thus, the use of the adiabatic meta-GGA opens a new path for handling the extreme non-locality of the time-dependent exchange-correlation potential in solid-state systems.

The first-principle calculation of the optical properties of semiconductors is a classic and practically important problem in electronic structure theory. The difficulty stems largely from the critical role played by electron-electron interactions, particularly the so-called excitonic effects, i.e. the interaction of an electron in the conduction band with the hole left behind in the valence band. Early calculations [1] based on diagrammatic many-body theory achieved good agreement with the experiment at the price of much computational effort. In recent years, the problem has been tackled by several authors [2], who made use of state-of-the-art methods such as the GW approximation for the electron self-energy and the Bethe-Salpeter equation for the electron-hole interaction. These methods are computationally demanding and not so easily adaptable to an emerging new generation of electronic materials, e.g. organic semiconductors and long polymer chains.

A promising alternative to the traditional many-body approach is provided by the time-dependent density functional theory (TDDFT) [3]. This approach directly targets the density-density (or, in some versions, the current-current [4]) response function of a fictitious non-interacting system, the so-called Kohn-Sham (KS) system, which is so designed as to produce (at least in principle) the same density/current response as the physical interacting system. The elimination of interactions greatly reduces the computational effort, but the complexity of the many-body problem eventually resurfaces, since the quality of the results is crucially determined by the quality of the (approximate) exchange-correlation (xc) potential $v_{xc}(\mathbf{r}, t)$ in which the fictitious non-interacting electrons move.

Successes and failures of the TDDFT approach to the calculation of optical spectra of semiconductor are well-documented. The first difficulty, which has been known since the early 1980s, is that the basic local-density ap-

proximation (LDA) and its semi-local extensions severely underestimate the band gap. The problem with the KS band gap can be corrected by the use of orbital-dependent functionals [5–7] [8] or the TDDFT approach can be implemented on top of a band-structure obtained by a many-body calculation [9–11]. However, even if the band-gap had been corrected, the calculation of the optical properties is not easy. The standard approach based on the adiabatic local density approximation (ALDA) [3], for example, dramatically underestimates the low energy peak – commonly referred to as the “excitonic peak” – in the optical spectrum. Improvements on the ALDA such as the adiabatic extension of the GGA do not fare much better. The exact exchange approach [6] has been found to catch the excitonic effect in silicon [12], but this was achieved at the cost of artificially restricting the set of states included in the calculation to avoid the “collapse” of the spectra. So far, the most consistent ab-initio scheme leading to results in good agreement with experiment has been the recasting of Bethe-Salpeter equation as an equation for a two-point function within the framework of TDDFT [10]; but even this approach remains computationally very demanding.

In recent years, a new class of approximate functionals has emerged in ground-state DFT. These are known as meta-GGA (MGGA) functionals and their defining characteristic is to depend not only on the density and its gradient, but also on the non-interacting kinetic energy density $\tau(\mathbf{r})$ [13–16]. At first sight, the dependence on $\tau(\mathbf{r})$ seems to contradict the general statement that the xc potential is a functional of the density. But, it must be kept in mind that $\tau(\mathbf{r})$ is determined by Kohn-Sham orbitals which, in turn, are nonlocal functionals of the density. Thus the MGGA functionals are still functionals of the density, but intrinsically nonlocal ones. Their power stems entirely from this fact.

In this Letter we show that an adiabatic approxima-

tion based on meta-GGA functionals leads to very significant improvement in the calculation of optical properties. The fact that meta-GGA functionals can lead to improvements in the calculation of the KS band gap has been known for some time [16]. What we add here to that knowledge is the realization that these functionals can also produce accurate optical spectra. And since the use of the adiabatic approximation automatically excludes retardation effects, we conclude that the primary reason for the success of the meta-GGA functionals is the improved treatment of the long-rangedness in the xc potential. This long-rangedness (often referred to as “ultranonlocality”) has long been known to be a problem in TDDFT, especially so in the applications to extended systems. While its strength could be inferred from fits to experimental spectra [9], none of the approximations developed so far could deal with it satisfactorily. We believe that the use of meta-GGA functionals is a breakthrough in the handling of ultranonlocality and paves the way to efficient first-principle calculations of the optical properties of semiconductors and more complex materials.

Formulation – The crucial quantity targeted in TDDFT is the density-density response function $\chi(\mathbf{r}, \mathbf{r}', \omega)$, which is related to the non-interacting KS response function $\chi_s(\mathbf{r}, \mathbf{r}', \omega)$ by the equation [3]

$$\chi^{-1}(\mathbf{r}, \mathbf{r}', \omega) = \chi_s^{-1}(\mathbf{r}, \mathbf{r}', \omega) - f_{xc}(\mathbf{r}, \mathbf{r}', \omega) - \frac{e^2}{|\mathbf{r} - \mathbf{r}'|}, \quad (1)$$

where $f_{xc}(\mathbf{r}, \mathbf{r}', \omega) = \delta v_{xc}(\mathbf{r}, \omega) / \delta n(\mathbf{r}', \omega)$ is the xc kernel,

defined as the functional derivative of the dynamic xc potential $v_{xc}(\mathbf{r}, \omega)$ with respect to the dynamic particle-density. In order to calculate f_{xc} we start from the expression for the xc energy within MGGA as

$$E_{xc} = \int \epsilon_{xc}[n(\mathbf{r}), \nabla n(\mathbf{r}), \tau(\mathbf{r})] d\mathbf{r}, \quad (2)$$

where the xc energy density ϵ_{xc} is a local function of its three arguments, $n(\mathbf{r})$ is the particle density,

$$\begin{aligned} \tau(\mathbf{r}) &= \frac{1}{2} \sum_{\alpha} f_{\alpha} |\nabla \psi_{\alpha}(\mathbf{r})|^2 \\ &= \sum_{\alpha} f_{\alpha} \epsilon_{\alpha} |\psi_{\alpha}(\mathbf{r})|^2 - v_s(\mathbf{r}) n(\mathbf{r}) + \frac{1}{4} \nabla^2 n(\mathbf{r}) \end{aligned} \quad (3)$$

is the non-interacting kinetic energy density, ψ_{α} , ϵ_{α} , and f_{α} are the KS orbitals, their eigenenergies, and the occupation numbers, respectively, and $v_s(\mathbf{r})$ is the static KS potential. The second equality in Eq. (3) follows from the KS equation. With the use of the definitions of the xc potential and the xc kernel as the first and the second functional derivatives of E_{xc} with respect to density, we derive from Eq. (2)

$$v_{xc}(\mathbf{r}) = \frac{\partial \epsilon_{xc}}{\partial n}(\mathbf{r}) - \nabla \frac{\partial \epsilon_{xc}}{\partial \nabla n}(\mathbf{r}) + \int \frac{\partial \epsilon_{xc}}{\partial \tau}(\mathbf{r}') \frac{\delta \tau(\mathbf{r}')}{\delta n(\mathbf{r})} d\mathbf{r}', \quad (4)$$

$$\begin{aligned} f_{xc}(\mathbf{r}, \mathbf{r}') &= \frac{\partial^2 \epsilon_{xc}}{\partial n^2}(\mathbf{r}) \delta(\mathbf{r} - \mathbf{r}') - \left[\nabla \frac{\partial^2 \epsilon_{xc}}{\partial n \partial \nabla n}(\mathbf{r}) \right] \delta(\mathbf{r} - \mathbf{r}') - \nabla_i \frac{\partial^2 \epsilon_{xc}}{\partial \nabla_i n \partial \nabla_j n}(\mathbf{r}) \nabla_j \delta(\mathbf{r} - \mathbf{r}') \\ &+ \frac{\partial^2 \epsilon_{xc}}{\partial n \partial \tau}(\mathbf{r}) \frac{\delta \tau(\mathbf{r})}{\delta n(\mathbf{r}')} + \frac{\partial^2 \epsilon_{xc}}{\partial n \partial \tau}(\mathbf{r}') \frac{\delta \tau(\mathbf{r}')}{\delta n(\mathbf{r})} - \nabla \frac{\partial^2 \epsilon_{xc}}{\partial \nabla n \partial \tau}(\mathbf{r}) \frac{\delta \tau(\mathbf{r})}{\delta n(\mathbf{r}')} - \nabla' \frac{\partial^2 \epsilon_{xc}}{\partial \nabla' n \partial \tau}(\mathbf{r}') \frac{\delta \tau(\mathbf{r}')}{\delta n(\mathbf{r})} \\ &+ \int \frac{\partial^2 \epsilon_{xc}}{\partial \tau^2}(\mathbf{r}'') \frac{\delta \tau(\mathbf{r}'')}{\delta n(\mathbf{r})} \frac{\delta \tau(\mathbf{r}'')}{\delta n(\mathbf{r}')} d\mathbf{r}'' + \int \frac{\partial \epsilon_{xc}}{\partial \tau}(\mathbf{r}'') \frac{\delta^2 \tau(\mathbf{r}'')}{\delta n(\mathbf{r}) \delta n(\mathbf{r}')} d\mathbf{r}''. \end{aligned} \quad (5)$$

The xc potential of Eq. (4) has been thoroughly addressed in Ref. 17 and our focus will be the xc kernel of Eq. (5). With the use of the standard perturbation theory, the functional derivatives of τ evaluate to [18]

$$\begin{aligned} \frac{\delta \tau(\mathbf{r})}{\delta n(\mathbf{r}')} &= -v_s(\mathbf{r}) \delta(\mathbf{r} - \mathbf{r}') \\ &+ \int H(\mathbf{r}, \mathbf{r}'') \chi_s^{-1}(\mathbf{r}'', \mathbf{r}') d\mathbf{r}'' + \frac{1}{4} \nabla^2 \delta(\mathbf{r} - \mathbf{r}'), \end{aligned} \quad (6)$$

$$\begin{aligned} \frac{\delta^2 \tau(\mathbf{r})}{\delta n(\mathbf{r}') \delta n(\mathbf{r}'')} &= -\delta(\mathbf{r} - \mathbf{r}') \chi_s^{-1}(\mathbf{r}, \mathbf{r}'') - \delta(\mathbf{r} - \mathbf{r}'') \chi_s^{-1}(\mathbf{r}, \mathbf{r}') \\ &+ 2 \int F(\mathbf{r}, \mathbf{r}_1, \mathbf{r}_2) \chi_s^{-1}(\mathbf{r}_1, \mathbf{r}') \chi_s^{-1}(\mathbf{r}_2, \mathbf{r}'') d\mathbf{r}_1 d\mathbf{r}_2 \end{aligned}$$

$$+ \int H(\mathbf{r}, \mathbf{r}_1) \chi_{s2}^{-1}(\mathbf{r}_1, \mathbf{r}', \mathbf{r}'') d\mathbf{r}_1, \quad (7)$$

where

$$H(\mathbf{r}, \mathbf{r}_1) = \frac{1}{2} \sum_{\alpha \neq \beta} \frac{(f_{\alpha} - f_{\beta})(\epsilon_{\alpha} + \epsilon_{\beta})}{\epsilon_{\alpha} - \epsilon_{\beta}} \psi_{\alpha}^*(\mathbf{r}) \psi_{\beta}(\mathbf{r}) \psi_{\alpha}(\mathbf{r}_1) \psi_{\beta}^*(\mathbf{r}_1), \quad (8)$$

$$\begin{aligned} F(\mathbf{r}, \mathbf{r}_1, \mathbf{r}_2) &= \sum_{\alpha \neq \beta \neq \gamma \neq \alpha} \frac{f_{\alpha} \epsilon_{\alpha} - f_{\beta} \epsilon_{\beta}}{(\epsilon_{\alpha} - \epsilon_{\beta})(\epsilon_{\alpha} - \epsilon_{\gamma})} [\psi_{\alpha}^*(\mathbf{r}_2) \psi_{\gamma}(\mathbf{r}_2) \\ &\times \psi_{\gamma}^*(\mathbf{r}) \psi_{\beta}(\mathbf{r}) \psi_{\alpha}(\mathbf{r}_1) \psi_{\beta}^*(\mathbf{r}_1) + (\mathbf{r} \leftrightarrow \mathbf{r}_1)] \\ &- \sum_{\alpha \neq \beta} \frac{f_{\alpha} - f_{\beta}}{(\epsilon_{\alpha} - \epsilon_{\beta})^2} \epsilon_{\beta} [|\psi_{\alpha}(\mathbf{r}_1)|^2 \psi_{\alpha}^*(\mathbf{r}_2) \psi_{\beta}(\mathbf{r}_2) \end{aligned}$$

$$\times \psi_\alpha(\mathbf{r})\psi_\beta^*(\mathbf{r}) + (\mathbf{r} \leftrightarrow \mathbf{r}_1) + (\mathbf{r}_1 \leftrightarrow \mathbf{r}_2)], \quad (9)$$

and χ_{s2}^{-1} in Eq. (7) is the inverse of the quadratic KS density-response function $\chi_{s2}(\mathbf{r}, \mathbf{r}', \mathbf{r}'') = \frac{\delta^2 n(\mathbf{r})}{\delta v_s(\mathbf{r}')\delta v_s(\mathbf{r}'')}$.

Equations (5)-(9) together with the explicit KS response functions [18] constitute the complete solution to the MGGA-based xc kernel f_{xc} .

Ultranonlocality – In reciprocal space, the xc kernel becomes a matrix in the reciprocal vectors $f_{xc, \mathbf{G}\mathbf{G}'}(\mathbf{q})$. Whether or not the MGGA for f_{xc} provides an improvement over conventional approximations depends on the presence or absence, in the optical limit $\mathbf{q} \rightarrow \mathbf{0}$, of a singularity of the type $f_{xc, \mathbf{0}\mathbf{0}}(\mathbf{q}) \simeq \alpha/q^2$ [9]. Obviously, LDA and GGA [the first three terms in Eq. (5)] do not have such a singularity. We can also show [18] that all the terms on the second line of Eq. (5) as well as the first term on the third line, do not contribute to the singularity of $f_{xc, \mathbf{0}\mathbf{0}}(\mathbf{q})$. As for the last term on the third line of Eq. (5), we simplify it by replacing the position-dependent quantity $\frac{\partial \epsilon_{xc}}{\partial \tau}(\mathbf{r})$ by its average over the unit cell – an approximation that is well justified, a posteriori, for the systems we have studied. With these approximations, we simplify f_{xc} to [18]

$$f_{xc, \mathbf{G}\mathbf{G}'}(\mathbf{q}) \approx -\frac{\overline{\partial \epsilon_{xc}}}{\partial \tau} \chi_{s, \mathbf{G}\mathbf{G}'}^{-1}(\mathbf{q}), \quad (10)$$

where the overline denotes the average over the unit cell. The right-hand side of Eq. (10) contains the singularity in question because χ_s^{-1} does [19]. Focusing on the $\mathbf{0}\mathbf{0}$ component, we finally get

$$\alpha = -\frac{\overline{\partial \epsilon_{xc}}}{\partial \tau} \lim_{\mathbf{q} \rightarrow \mathbf{0}} q^2 \chi_{s, \mathbf{0}\mathbf{0}}^{-1}(\mathbf{q}). \quad (11)$$

Considering that $\overline{\partial \epsilon_{xc}/\partial \tau}$ is almost the same for Si and Ge, neglecting for a moment the local-field effects, and neglecting the unity compared to the static dielectric function of a semiconductor, we see that Eq. (11) is in agreement with the empirical rule of α being inversely proportional to the dielectric function [11], [20]. We also note that the ultranonlocality we find seems to be the first explicit demonstration of the fact that the kinetic energy-dependent functionals are not in practice semi-local in the density [7].

Choice of functionals and calculation of optical properties – Having established on the fundamental level that the adiabatic meta-GGA-based TDDFT does account for the ultra-nonlocality in crystals, we now turn to numerical calculations. First we note that only the group of functionals that provide E_{xc} (e.g, VS98 [13] and TPSS [14]) rather than those providing v_{xc} directly (e.g., BJ06 [15] and TB09 [16]) can be used to build f_{xc} , since for the functionals of the latter group the corresponding E_{xc} does not exist [16]. We have used two well established

TABLE I. The average over the unit cell of the derivative of the exchange, correlation, and xc energy density with respect to the kinetic energy density found for Si and Ge with the VS98 [13] and TPSS [14] functionals.

	VS98			TPSS		
	$\overline{\partial \epsilon_x/\partial \tau}$	$\overline{\partial \epsilon_c/\partial \tau}$	$\overline{\partial \epsilon_{xc}/\partial \tau}$	$\overline{\partial \epsilon_x/\partial \tau}$	$\overline{\partial \epsilon_c/\partial \tau}$	$\overline{\partial \epsilon_{xc}/\partial \tau}$
Si	0.122	-0.226	-0.104	4.60×10^{-3}	-1.15×10^{-4}	4.49×10^{-3}
Ge	0.135	-0.241	-0.106	2.94×10^{-3}	8.73×10^{-5}	3.03×10^{-3}

MGGA functionals VS98 [13] and TPSS [14] for the calculation of both the ground-state with v_{xc} of Eq. (4) and f_{xc} of Eq. (10) [21]. The resulting values of the key quantity $\partial \epsilon_{xc}/\partial \tau$ entering Eq. (10) are listed in Table I. At first glance surprisingly, the values found with the two different functionals differ drastically: The τ -dependent part of the TPSS functional was found negligible everywhere over the unit cell. In the supplemental material [18], we analyze the τ -dependence of VS98 and TPSS functionals to the conclusion that for the latter it is very weak. Accordingly, we argue that while well-tuned to yield accurate E_{xc} , TPSS performs unsatisfactorily with respect to its τ -derivative. A clear reason for the weak τ -dependence of TPSS can then be easily identified: This functional is tuned to (i) the nearly free electron gas (NFEG) and (ii) the one- and two-electron systems [14]. In both cases, due to the gradient expansion of the kinetic energy of NFEG and to the von Weizsäcker's formula for the kinetic energy of one and two electron systems, respectively, τ is (semi-)local in density, which leads to the local theory with respect to f_{xc} and zero α (Cf. [22]). On the other hand, the VS98 functional is designed to work better in the strong inhomogeneity case [13], which qualitatively explains its success in yielding realistic values of α . We believe that the ability to yield an accurate value of α should be added from now on to the list of basic requirements that a good xc functional must satisfy.

We calculated the KS band-structure and the microscopic density-response matrix of Si and Ge with the full-potential linear augmented plane-wave (FP-LAPW) method and the VS98 MGGA xc functional [23]. The supporting results for zincblende semiconductors are presented in [18]. The real and imaginary parts of the macroscopic ($\mathbf{q} = \mathbf{0}$) dielectric function are presented in Figs. 1 and 2. It is evident that the inclusion of the non-local f_{xc} of Eq. (10) via the MGGA greatly improves the agreement between the theory and experiment, in particular, making the excitonic peak considerably more pronounced. We note that as adiabatic and, consequently, real, our f_{xc} has no effect on the band gap. Therefore, in Figs. 1 and 2 the TDDFT and RPA band gaps are the same, determined by the KS excitation spectrum.

It is instructive to draw a parallel between our approach and that of Ref. 9. Before the inclusion of f_{xc} , both methods produce single-particle spectra that un-

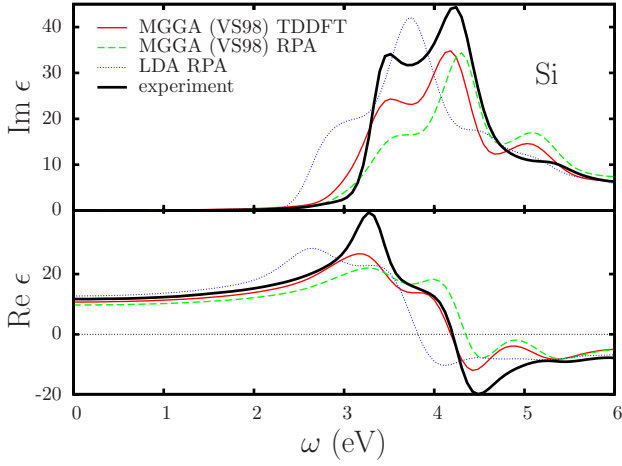


FIG. 1. (color online) Dielectric function of silicon. Thin solid (red online) line is the result obtained with MGGA band-structure and including the many-body interactions through f_{xc} of Eq. (10). Dashed (green online) line is the result obtained with MGGA band-structure but with $f_{xc} = 0$ (RPA). Dotted (blue online) line is obtained with LDA band-structure within RPA. Thick solid line is the experiment from Ref. 24.

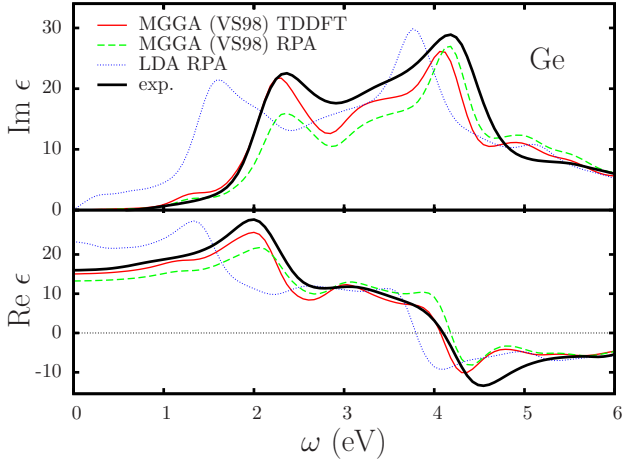


FIG. 2. (color online) The same as Fig. 1 but for germanium.

derestimate the intensity of the excitonic peak. Then, with the inclusion of the many-body interactions through f_{xc} , the spectra are red-shifted and the excitonic feature grows. The fundamental differences between the two approaches are that: (i) We remain all the time within the framework of TDDFT, while Ref. 9 uses a combination of TDDFT with the GW approximation of many-body theory; (ii) While the quantity α in Ref. 9 was a fitting parameter, we have for it an explicit expression, Eq. (11), derived from an xc-energy functional. In this regard, we note that an MGGA functional is the simplest type of functional that produces an ultra-nonlocal f_{xc} in an adiabatic approximation. Moreover, for Si, Eq. (11) evaluates to $\alpha = -0.267$, which compares reasonably well with the best fit value of Ref. 9 of $\alpha = -0.2$ [25].

To further explore the range of applicability of our theory, we have carried out calculations for the wide-gap insulator LiF to the result that with the approximation (10), the value of $\partial\epsilon_{xc}/\partial\tau$ is too small to account for the bound exciton. With regard to this challenge, a full numerical implementation of the “exact” MGGA f_{xc} of Eq. (5) seems a promising approach [18].

In conclusion, we have developed the adiabatic TDDFT formalism for the kinetic energy dependent (MGGA) exchange-correlation functionals. In contrast to LDA and GGA approximations, the resulting exchange-correlation kernel f_{xc} is shown to exhibit the singularity of the type α/q^2 , which is a necessary feature for a theory to describe the excitonic effect in crystals. Our calculations performed for a number of the diamond-structure and zincblende semiconductors demonstrate the high promise of the MGGA-based exchange-correlation functionals as a new tool in the arsenal of TDDFT methods.

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